



DMP3050LVT

#### P-CHANNEL ENHANCEMENT MODE MOSFET

# **Product Summary**

| BV <sub>DSS</sub> | R <sub>DS(ON)</sub> Max        | I <sub>D</sub> Max<br>T <sub>A</sub> = +25°C |
|-------------------|--------------------------------|--|
| 001/              | 50mΩ @ V <sub>GS</sub> = -10V  | -4.5A  |
| -30V              | 75mΩ @ V <sub>GS</sub> = -4.5V | -3.7A  |

### Description

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

#### Features

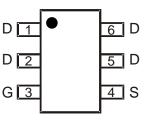
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

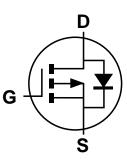
- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.013grams (Approximate)







**Device Schematic** 



Equivalent Circuit

## Ordering Information (Note 4)

| Part Number  | Case   | Packaging        |  |  |  |  |
|--|--------|------------------|--|--|--|--|
| DMP3050LVT-7   | TSOT26 | 3000/Tape & Reel |  |  |  |  |
| Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. |        |                  |  |  |  |  |

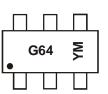
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



G64 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$ = Year (ex: D = 2016) M = Month (ex: 9 = September)

| Date Code Key |      |     |     |      |      |     |     |      |      |     |     |      |
|---------------|------|-----|-----|------|------|-----|-----|------|------|-----|-----|------|
| Year          | 2011 |     | ~   | 2016 | 2017 | 20  | 18  | 2019 | 2020 | 20  | )21 | 2022 |
| Code          | Y    |     | ~   | D    | E    |     | F   | G    | Н    |     | I   | J    |
| Month         | Jan  | Feb | Mar | Apr  | May  | Jun | Jul | Aug  | Sep  | Oct | Nov | Dec  |
| Code          | 1    | 2   | 3   | 4    | 5    | 6   | 7   | 8    | 9    | 0   | N   | D    |



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic   |                 | Symbol   | Value | Unit         |   |
|--|-----------------|--|-------|--------------|---|
| Drain-Source Voltage                                     |                 | V <sub>DSS</sub>                                 | -30   | V            |   |
| Gate-Source Voltage (Note 5)                             |                 | V <sub>GSS</sub>                                 | ±25   | V            |   |
|  | Steady<br>State | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | ID    | -4.5<br>-3.5 | A |
| Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V | t<10s           | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | ID    | -5.2<br>-4.1 | А |
| Maximum Continuous Body Diode Forward Current            | t (Note 6)      | ls   | -2    | A            |   |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%        | 6)              | I <sub>DM</sub>                                  | -25   | А            |   |

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic   |                        | Symbol                           | Value       | Unit |  |
|--|------------------------|----------------------------------|-------------|------|--|
| Total Power Dissipation (Note 6)                           | T <sub>A</sub> = +25°C | Π-                               | 1.6         | W    |  |
|  | T <sub>A</sub> = +70°C | PD                               | 1.0         |      |  |
| Thermal Resistance, Junction to Ambient (Note 6)           | Steady State           | P                                | 78          | °C/W |  |
| mermar Resistance, Junction to Ambient (Note 6)            | t<10s                  | $R_{	extsf{	heta}JA}$            | 49          |      |  |
| Thermal Resistance, Junction to Case (Note 6) Steady State |                        | $R_{\theta JC}$                  | 13          |      |  |
| Operating and Storage Temperature Range                    |                        | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150 | °C   |  |

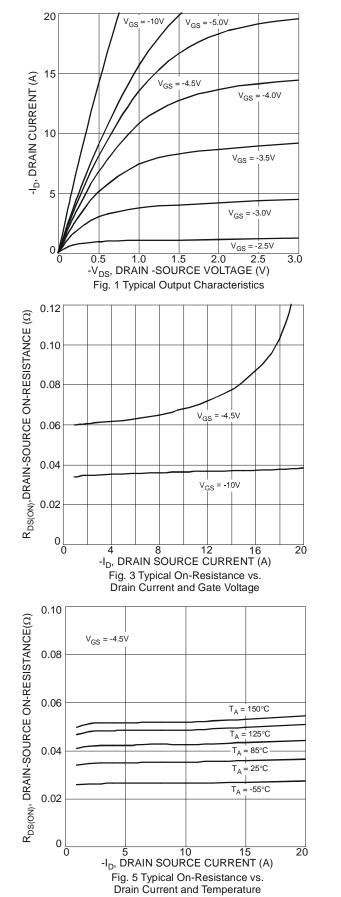
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

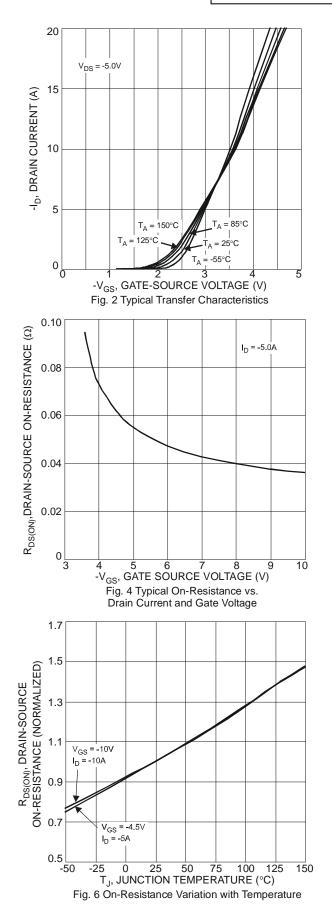
| Characteristic                              | Symbol              | Min  | Тур  | Max  | Unit   | Test Condition  |
|---|---------------------|------|------|------|--------|---|
| OFF CHARACTERISTICS (Note 7)                |                     |      | -    |      |        |   |
| Drain-Source Breakdown Voltage              | BV <sub>DSS</sub>   | -30  | -    | -    | V      | $V_{GS} = 0V, I_D = -250 \mu A$                               |
| Zero Gate Voltage Drain Current             | I <sub>DSS</sub>    | -    | -    | -1   | μA     | $V_{DS} = -30V, V_{GS} = 0V$                                  |
| Gate-Source Leakage                         | I <sub>GSS</sub>    | -    | -    | ±100 | nA     | $V_{GS} = \pm 20V, V_{DS} = 0V$                               |
| ON CHARACTERISTICS (Note 7)                 |                     |      |      |      |        |   |
| Gate Threshold Voltage                      | V <sub>GS(TH)</sub> | -1.0 | -    | -2.0 | V      | $V_{DS} = V_{GS}, I_D = -250 \mu A$                           |
| Static Drain-Source On-Resistance           | <b>D</b>            | -    | 36   | 50   | mΩ     | $V_{GS} = -10V, I_D = -4.5A$                                  |
|   | R <sub>DS(ON)</sub> | -    | 56   | 75   | 1115.2 | $V_{GS} = -4.5V, I_D = -3A$                                   |
| Forward Transfer Admittance                 | Y <sub>fs</sub>     | -    | 7.2  | -    | S      | $V_{DS} = -5V, I_D = -5A$                                     |
| Diode Forward Voltage                       | V <sub>SD</sub>     | -    | -0.7 | -1.0 | V      | $V_{GS} = 0V, I_{S} = -1A$                                    |
| DYNAMIC CHARACTERISTICS (Note 8)            |                     |      |      |      |        |   |
| Input Capacitance                           | Ciss                | -    | 620  | -    | pF     |   |
| Output Capacitance                          | C <sub>oss</sub>    | -    | 83   | -    | pF     | −V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V,<br>−f = 1.0MHz |
| Reverse Transfer Capacitance                | Crss                | -    | 62   | -    | pF     | 1 = 1.00012   |
| Gate Resistance                             | Rg                  | -    | 10.8 | -    | Ω      | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$                        |
| Total Gate Charge (V <sub>GS</sub> = -4.5V) | Qg                  | -    | 5.1  | -    | nC     |   |
| Total Gate Charge (V <sub>GS</sub> = -10V)  | Qg                  | -    | 10.5 | -    | nC     | V <sub>DS</sub> = -15V, I <sub>D</sub> = -6A                  |
| Gate-Source Charge                          | Q <sub>gs</sub>     | -    | 1.8  | -    | nC     | $v_{\rm DS} = -15 v, 10 = -0A$                                |
| Gate-Drain Charge                           | Q <sub>gd</sub>     | -    | 1.9  | -    | nC     |   |
| Turn-On Delay Time                          | t <sub>D(ON)</sub>  | -    | 6.8  | -    | ns     |   |
| Turn-On Rise Time                           | t <sub>R</sub>      | -    | 4.9  | -    | ns     | $V_{DD} = -15V, V_{GS} = -10V,$                               |
| Turn-Off Delay Time                         | t <sub>D(OFF)</sub> | -    | 28.4 | -    | ns     | $R_g = 6\Omega, I_D = -1A$                                    |
| Turn-Off Fall Time                          | t <sub>F</sub>      | -    | 12.4 | -    | ns     |   |

Notes:

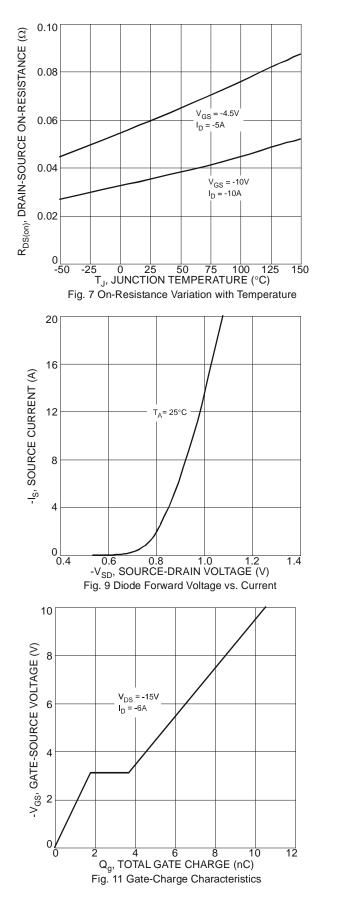
5. AEC-Q101 V<sub>GS</sub> maximum is ±20V.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

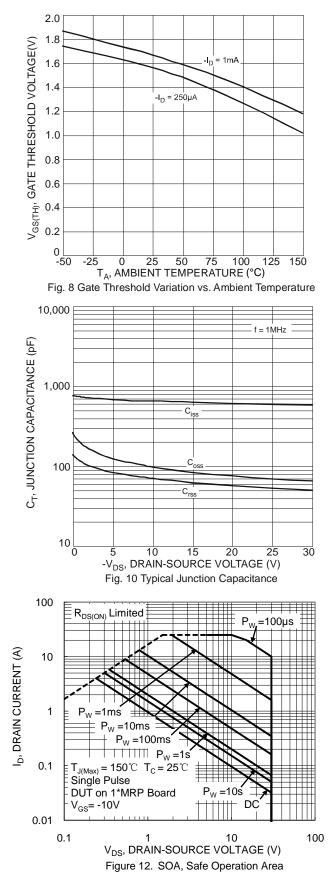






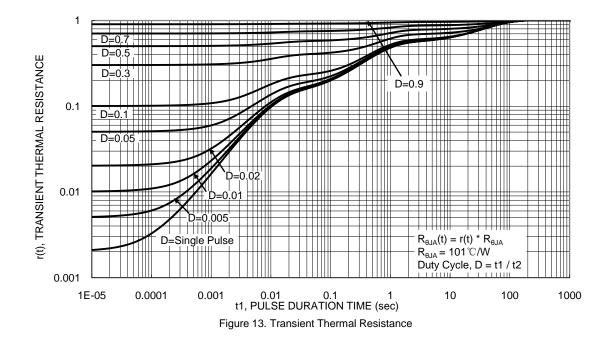








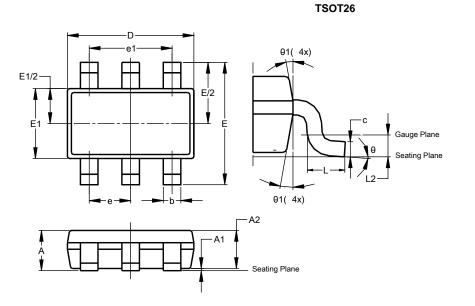






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

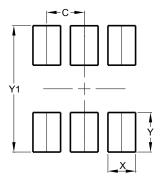


| TSOT26 |                      |           |       |  |  |  |  |
|--------|----------------------|-----------|-------|--|--|--|--|
| Dim    | Min                  | Max       | Тур   |  |  |  |  |
| Α      | -                    | - 1.00    |       |  |  |  |  |
| A1     | 0.010                | 0.100     | -     |  |  |  |  |
| A2     | 0.840                | 0.900     | -     |  |  |  |  |
| D      | 2.800                | 3.000     | 2.900 |  |  |  |  |
| ш      | 2                    | .800 BS   | С     |  |  |  |  |
| E1     | 1.500                | 1.700     | 1.600 |  |  |  |  |
| b      | 0.300                | 0.450     | -     |  |  |  |  |
| С      | 0.120                | 0.200     | -     |  |  |  |  |
| е      | 0.950 BSC            |           |       |  |  |  |  |
| e1     | 1                    | 1.900 BSC |       |  |  |  |  |
| L      | 0.30 0.50 -          |           | -     |  |  |  |  |
| L2     | 0.250 BSC            |           |       |  |  |  |  |
| θ      | 0°                   | 8°        | 4°    |  |  |  |  |
| θ1     | 4°                   | 12°       | -     |  |  |  |  |
| A      | All Dimensions in mm |           |       |  |  |  |  |

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSOT26



| Dimensions | Value (in mm) |  |  |  |
|------------|---------------|--|--|--|
| С          | 0.950         |  |  |  |
| Х          | 0.700         |  |  |  |
| Y          | 1.000         |  |  |  |
| Y1         | 3.199         |  |  |  |



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